CBCX68 SERIES NPN CBCX69 SERIES PNP

SURFACE MOUNT COMPLEMENTARY SILICON SMALL SIGNAL TRANSISTORS



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR CBCX68 and CBCX69 series types are complementary silicon transistors manufactured by the epitaxial planar process, epoxy molded in a surface mount package, designed for applications requiring high current capability.

MARKING: FULL PART NUMBER



MAXIMUM RATINGS: (T _A =25°C)	SYMBOL		UNITS
Collector-Emitter Voltage	V _{CES}	25	V
Collector-Emitter Voltage	V_{CEO}	20	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continous Collector Current	l _C	1.0	Α
Peak Collector Current	I _{CM}	2.0	Α
Continuous Base Current	I _B	100	mA
Peak Base Current	I _{BM}	200	mA
Power Dissipation	P_{D}	1.2	W
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +150	°C
Thermal Resistance	$\Theta_{\sf JA}$	104	°C/W

ELECTRICAL CHARACTERISTICS: (T _A =25°C unless otherwise noted)							
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS		
I _{CBO}	V _{CB} =25V			100	nA		
I _{CBO}	V _{CB} =25V, T _A =150°C			10	μΑ		
I _{EBO}	V _{EB} =5.0V			10	μΑ		
BV _{CBO}	$I_C=10\mu A$	25			V		
BVCEO	I _C =10mA	20			V		
BVEBO	I _E =10μA	5.0			V		
V _{CE(SAT)}	I _C =1.0A, I _B =100mA			0.5	V		
V _{BE(ON)}	V_{CE} =10V, I_{C} =5.0mA		0.6		V		
V _{BE(ON)}	V_{CE} =1.0V, I_{C} =1.0A			1.0	V		
h _{FE}	V_{CE} =10V, I_{C} =5.0mA	50					
hFE	V _{CE} =1.0V, I _C =500mA (CBCX68, CBCX69)	85		375			
h _{FE}	V _{CE} =1.0V, I _C =500mA (CBCX68-16, CBCX69-16)	100		250			
h _{FE}	V _{CE} =1.0V, I _C =500mA (CBCX68-25, CBCX69-25)	160		400			
h _{FE}	V_{CE} =1.0V, I_{C} =1.0A	60					
f_{T}	V_{CE} =5.0V, I_{C} =10mA, f=20MHz	65			MHz		

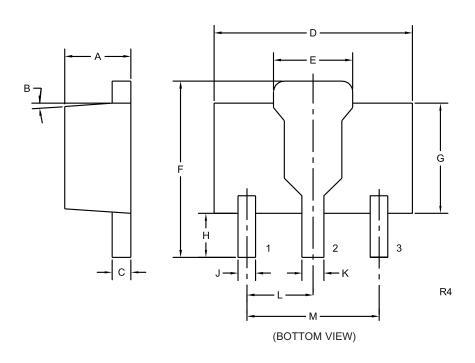
R11 (23-February 2012)

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SOT-89 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) EMITTER
- 2) COLLECTOR
- 3) BASE

MARKING:

FULL PART NUMBER

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.055	0.067	1.40	1.70			
В	4°		4°				
С	0.014	0.018	0.35	0.46			
D	0.173	0.185	4.40	4.70			
Е	0.064	0.074	1.62	1.87			
F	0.146	0.177	3.70	4.50			
G	0.090	0.106	2.29	2.70			
Н	0.028	0.051	0.70	1.30			
J	0.014	0.019	0.36	0.48			
K	0.017	0.023	0.44	0.58			
Ĺ	0.059		1.50				
М	0.118		3.00				

SOT-89 (REV: R4)

R11 (23-February 2012)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA

Main Tel: (631) 435-1110 Main Fax: (631) 435-1824

Support Team Fax: (631) 435-3388

www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

Worldwide Distributors:

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